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October 1987 Revised January 1999

CD40106BC Hex Schmitt Trigger

General Description

The CD40106BC Hex Schmitt Trigger is a monolithic complementary MOS (CMOS) integrated circuit constructed with N and P-channel enhancement transistors. The positive and negative-going threshold voltages, V_{T+} and V_{T-} , show low variation with respect to temperature (typ 0.0005V/°C at $V_{DD}=10V),$ and hysteresis, $V_{T+}-V_{T-}\geq 0.2$ V_{DD} is guaranteed.

All inputs are protected from damage due to static discharge by diode clamps to V_{DD} and V_{SS} .

Features

- Wide supply voltage range: 3V to 15V
- High noise immunity: 0.7 V_{DD} (typ.)
- Low power TTL compatibility:

Fan out of 2 driving 74L or 1 driving 74LS

- Hysteresis: 0.4 V_{DD} (typ.), 0.2 V_{DD} guaranteed
- Equivalent to MM74C14
- Equivalent to MC14584B

Ordering Code:

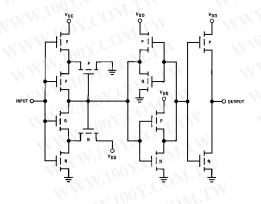
Order Number	Package Number	Package Description			
CD40106BCM	M14A	14-Lead Small Outline integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body			
CD40106BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP) JEDEC MS-001_0 300" Wide			

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignments for DIP and SOIC VDD 14 13 12 11 10 9 8 Top View

Schematic Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

DC Supply Voltage (V_{DD}) -0.5 to +18 V_{DC} Input Voltage (V_{IN}) -0.5 to V_{DD} +0.5 V_{DC} Storage Temperature Range (T_S) -65°C to +150°C

Power Dissipation (P_D)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature (T_L)

260°C (Soldering, 10 seconds)

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD}) 3 to 15 V_{DC} Input Voltage (V_{IN}) 0 to V_{DD} V_{DC}

Operating Temperature Range (T_A) -40°C to +85°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: $V_{SS} = 0V$ unless otherwise specified.

DC Electrical Characteristics (Note 3)

Symbol	Parameter	Conditions	-40°C		+25°C			+85°C		Units
Symbol	Parameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Device Current	$V_{DD} = 5V$	10-	4.0			4.0	_ 1 1	30	μА
	COMP	V _{DD} = 10V	Obs	8.0	J		8.0	1111.	60	μА
	TIT	V _{DD} = 15V		16.0			16.0	-TXX	120	μΑ
V _{OL}	LOW Level Output	I _O < 1 μA	00,	-	(A)		11	MA A	. 0	1.10
N.100	Voltage	$V_{DD} = 5V$		0.05			0.05	-11	0.05	٧
	V.COI	V _{DD} = 10V		0.05	W		0.05	111	0.05	V
	2011:1	V _{DD} = 15V	1.0	0.05	1	r	0.05	1	0.05	٧
V _{OH}	HIGH Level Output	I _O < 1 μA	M.		TV			M	-1	100
	Voltage	$V_{DD} = 5V$	4.95	401	4.95	5		4.95	NW	٧
W V	MY. CONTRACTOR	V _{DD} = 10V	9.95	_	9.95	10		0.95		V
	Too COMP.	V _{DD} = 15V	14.95	CO	14.95	15		14.95		V
- 4 %	Negative-Going Threshold	$V_{DD} = 5V, V_{O} = 4.5V$	0.7	2.0	0.7	1.4	2.0	0.7	2.0	V
	Voltage	$V_{DD} = 10V, V_{O} = 9V$	1.4	4.0	1.4	3.2	4.0	1.4	4.0	V
	$\sim 100^{11}$	$V_{DD} = 15V, V_{O} = 13.5V$	2.1	6.0	2.1	5.0	6.0	2.1	6.0	V
	Positive-Going Threshold	$V_{DD} = 5V, V_{O} = 0.5V$	3.0	4.3	3.0	3.6	4.3	3.0	4.3	V
	Voltage	$V_{DD} = 10V, V_{O} = 1V$	6.0	8.6	6.0	6.8	8.6	6.0	8.6	V
	M. CO.	$V_{DD} = 15V, V_{O} = 1.5V$	9.0	12.9	9.0	10.0	12.9	9.0	12.9	V
- T N	Hysteresis (V _{T+} – V _{T-})	$V_{DD} = 5V$	1.0	3.6	1.0	2.2	3.6	1.0	3.6	V
	Voltage	V _{DD} = 10V	2.0	7.2	2.0	3.6	7.2	2.0	7.2	٧
	WW.IV	V _{DD} = 15V	3.0	10.8	3.0	5.0	10.8	3.0	10.8	V
OL	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.52	170	0.44	0.88	F. F.	0.36		mA
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 0.5V$	1.3		1.1	2.25	- 1	0.9		mA
	M	$V_{DD} = 15V, V_{O} = 1.5V$	3.6	V.1	3.0	8.8	Mer	2.4		mA
ГОН	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.52		-0.44	-0.88	- 11	-0.36		mA
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 9.5V$	-1.3	W.	-1.1	-2.25	Divr.	-0.9		mA
	MM	$V_{DD} = 15V, V_{O} = 13.5V$	-3.6		-3.0	-8.8		-2.4		mA
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$	-41	-0.30		-10 ⁻⁵	-0.30		-1.0	μΑ
		$V_{DD} = 15V, V_{IN} = 15V$		0.30	-110	10 ⁻⁵	0.30	1.7	1.0	μΑ

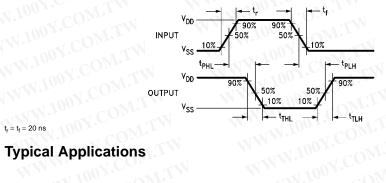
WWW.100Y.COM.TW WWW.100Y.COM.TW AC Electrical Characteristics (Note 4)

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) pF, $R_L = 200k$, t_r and $t_f = 20$ ns, unless of	otherwise specified				
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHL} or t _{PLH}	Propagation Delay Time from	$V_{DD} = 5V$	1/1/1/1	220	400	ns
	Input to Output	$V_{DD} = 10V$		80	200	ns
	100	V _{DD} = 15V		70	160	ns
t _{THL} or t _{TLH}	Transition Time	$V_{DD} = 5V$	41	100	200	ns
	10	$V_{DD} = 10V$		50	100	ns
	TAN WIN.	V _{DD} = 15V	1	40	80	ns
C _{IN}	Average Input Capacitance	Any Input		5	7.5	pF
C _{PD}	Power Dissipation Capacity	Any Gate (Note 5)		14	- 4 01	pF

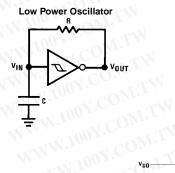
Note 5: CPD determines the no load ac power consumption of any CMOS device. For complete explanation see 74C Family Characteristics Application Note,

Switching Time Waveforms



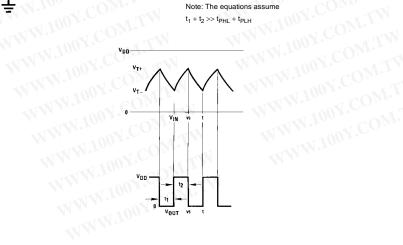
 $t_r = t_f = 20 \text{ ns}$

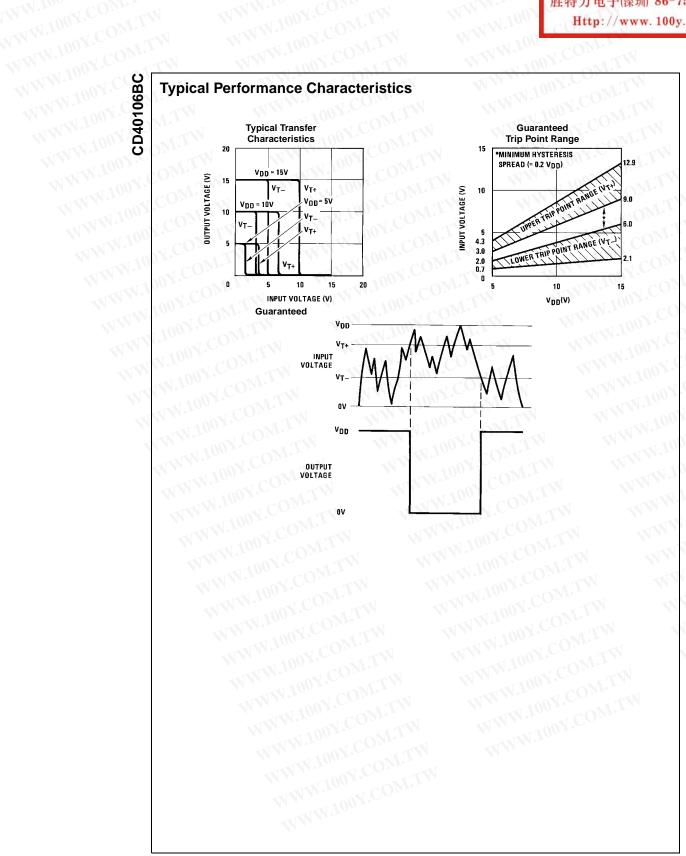
Typical Applications

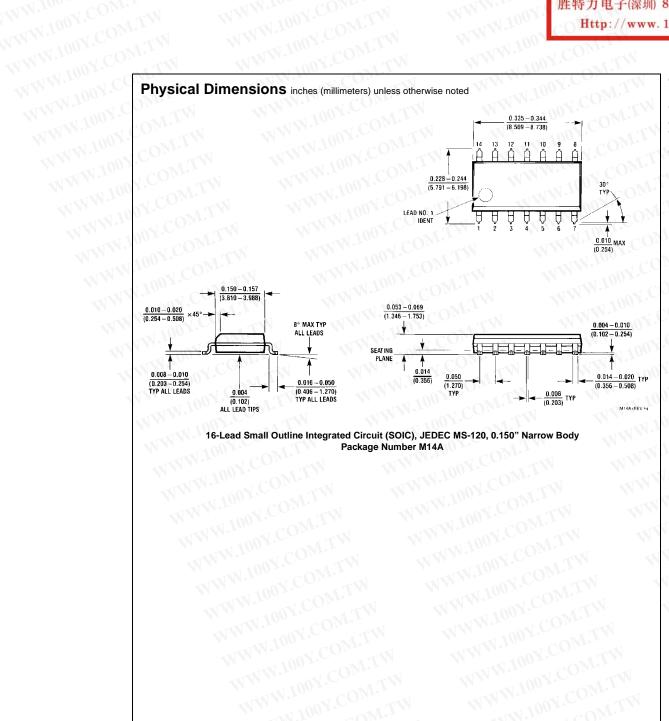


$$\begin{split} t_1 &\approx \text{RC } \ell \, n \, \frac{V_{T+}}{V_{T-}} \\ t_2 &\approx \text{RC } \ell \, n \, \frac{V_{DD} - V_{T-}}{V_{DD} - V_{T+}} \\ f &\approx \frac{1}{\text{RC } \ell \, n \, \frac{V_{T+} \left(V_{DD} - V_{T-}\right)}{V_{T-} \left(V_{DD} - V_{T+}\right)}} \end{split}$$

Note: The equations assume $t_1 + t_2 >> t_{PHI} + t_{PIH}$

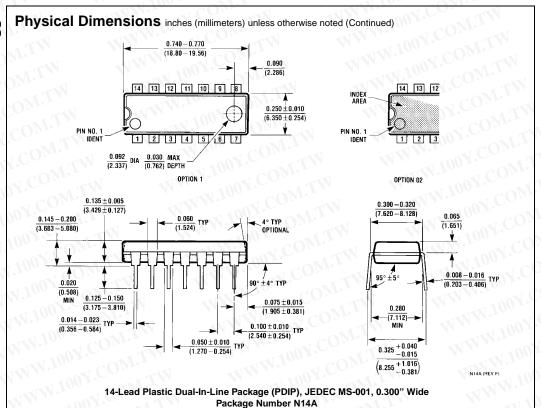






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